



DMP3056L

Product Summary

BV _{DSS}	Rds(on) max	I _{D MAX} T _A = +25°C	
-30V	50mΩ @ V _{GS} =-10V	-4.3A	
-30 V	70mΩ @ V _{GS} =-4.5V	-3.7A	

Description and Applications

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

SOT23

30V P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)

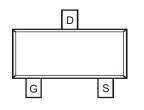
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.009 grams (Approximate)

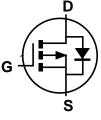
Connections: See Diagram



Top View



Top View Pin Configuration



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3056L-7	SOT23	3000/Tape & Reel
DMP3056L-13	SOT23	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

6L	ΥM

6L = Product Type Marking CodeYM = Date Code Marking $Y or <math>\overline{Y}$ = Year (ex: H = 2020) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Notes:

Year	2017			2020	2021	2022	2023	2024	4 20	25	2026	2027	2028
Code	E			Н		J	K	L	Ν	Λ	Ν	0	Р
Mont	h	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristi	•		Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage		V _{GSS}	±25	V	
Drain Current (Note 5) V _{GS} = -10V	ID	-4.3 -3.4	A		
Pulsed Drain Current (Note 6)			I _{DM}	-20	А

Thermal Characteristics

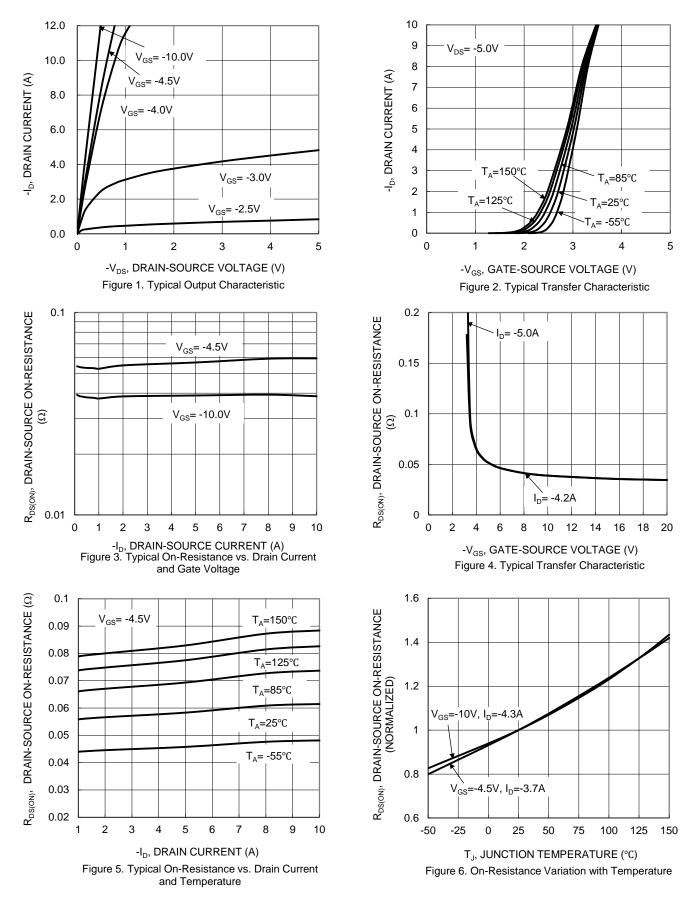
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.38	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ ext{ heta}JA}$	91	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

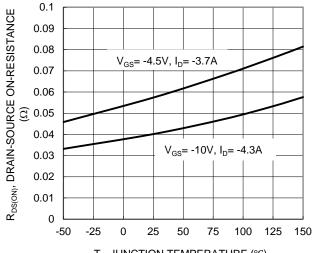
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
DFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30		_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_		-1	μA	$V_{DS} = -30V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100 ±800	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-1		-2.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}		35 50	50 70	mΩ	V _{GS} = -10V, I _D = -6.0A V _{GS} = -4.5V, I _D = -5.0A
Diode Forward Voltage	V _{SD}			-1.2	V	V _{GS} = 0V, I _S = -1.7A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}		642		pF	
Output Capacitance	Coss		65		pF	$V_{DS} = -25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	C _{rss}		48	_	pF	
Gate Resistance	R _G	_	15	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$
Total Gate Charge ($V_{GS} = -4.5V$)	Q_{G}		5.8	_	nC	$V_{DS} = -15V, I_D = -6A$
Total Gate Charge (V _{GS} = -10V)	Q _G		11.8			
Gate-Source Charge	Q _{GS}		2.0	_	nC	V _{DS} = -15V, I _D = -6A
Gate-Drain Charge	Q _{GD}	_	2.4	_		
Turn-On Delay Time	t _{D(ON)}		4.9	_		
Rise Time	t _R		4.7	_		V _{DS} = -15V, V _{GS} = -10V,
Turn-Off Delay Time	t _{D(OFF)}	_	35.2	_	ns	$I_D = -1A, R_G = 6.0\Omega$
Fall Time	t _F	_	18.2	_		

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
6. Pulse width ≤10µS, Duty Cycle ≤1%.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing. Notes:

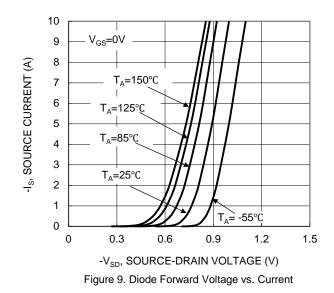


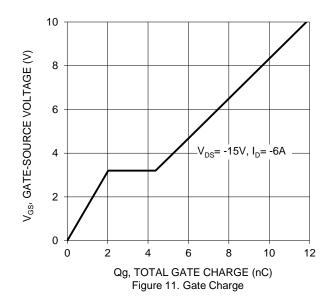


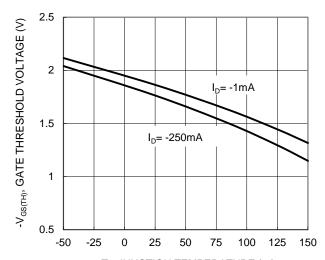




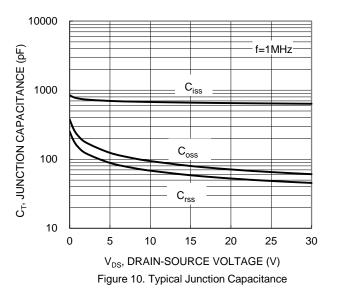


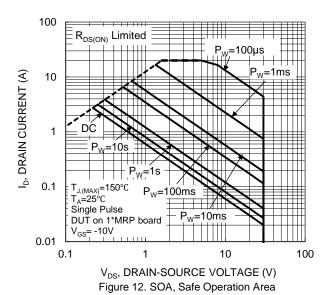






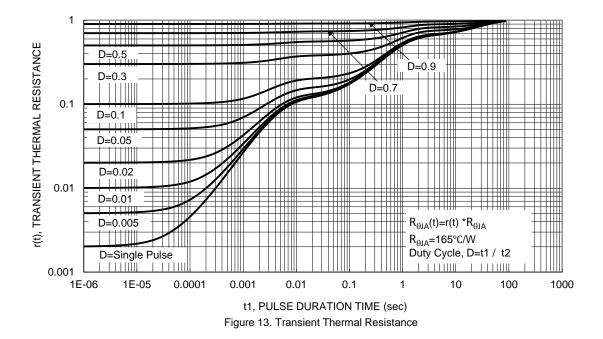
T_J, JUNCTION TEMPERATURE (°C) Figure 8. Gate Threshold Variation vs. Junction Temperature





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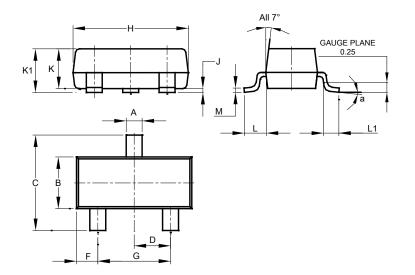






Package Outline Dimensions

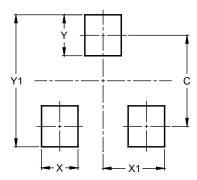
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
ĸ	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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